



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

P-Channel Silicon MOSFET

SCH1343 — General-Purpose Switching Device Applications

Features

- ON-resistance $R_{DS(on)1}=55m\Omega$ (typ.)
- 1.8V drive
- Halogen free compliance
- Protection diode in

Specifications

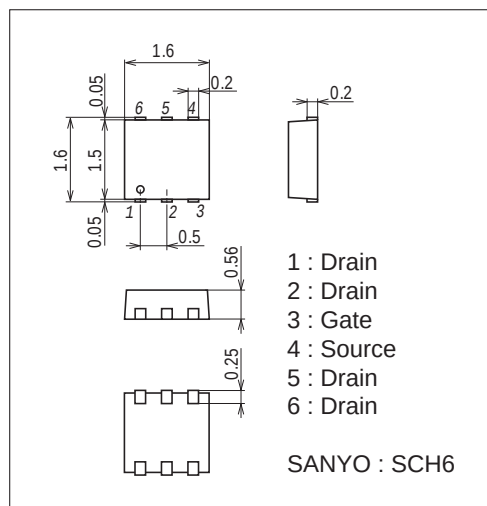
Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-20	V
Gate-to-Source Voltage	V_{GSS}		± 10	V
Drain Current (DC)	I_D		-3.5	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	-14	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (900mm ² ×0.8mm)	1	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Package Dimensions

unit : mm (typ)

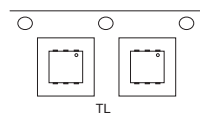
7028-002



Product & Package Information

- Package : SCH6
- JEITA, JEDEC : SOT-563
- Minimum Packing Quantity : 5,000 pcs./reel

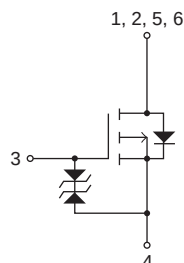
Packing Type : TL



Marking



Electrical Connection

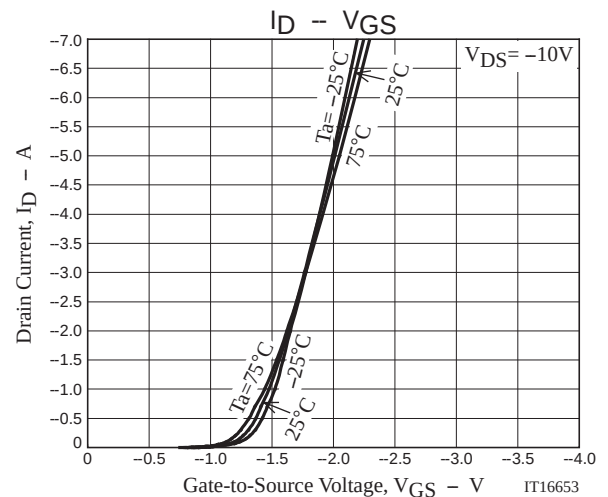
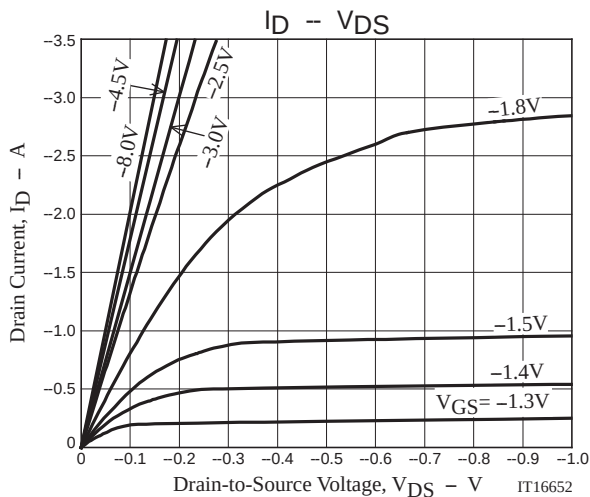
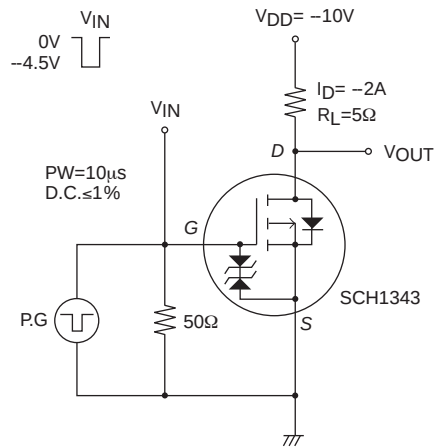


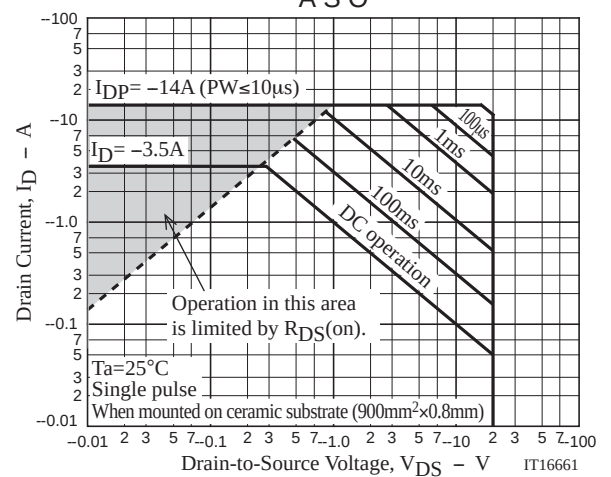
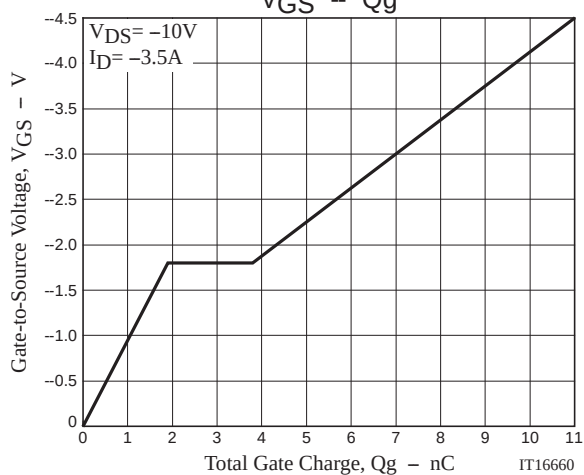
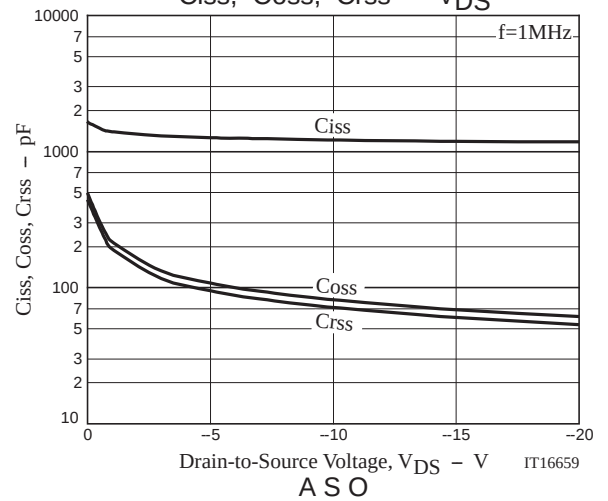
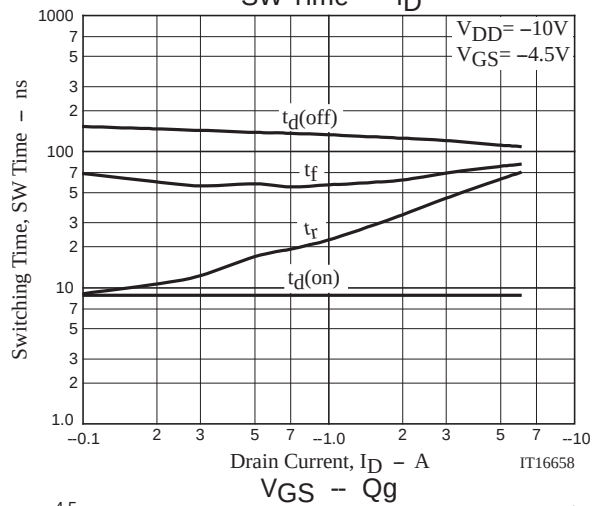
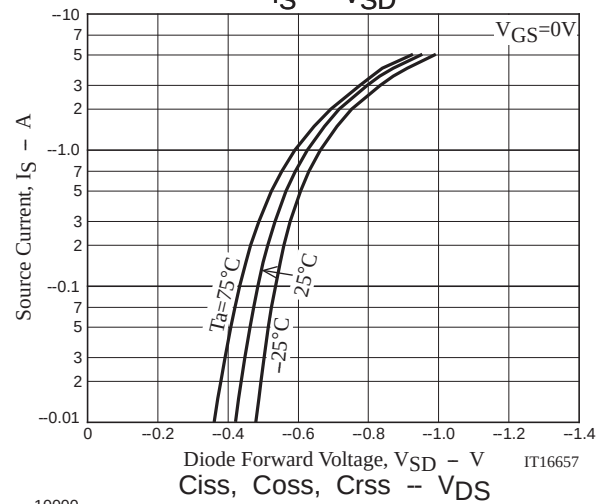
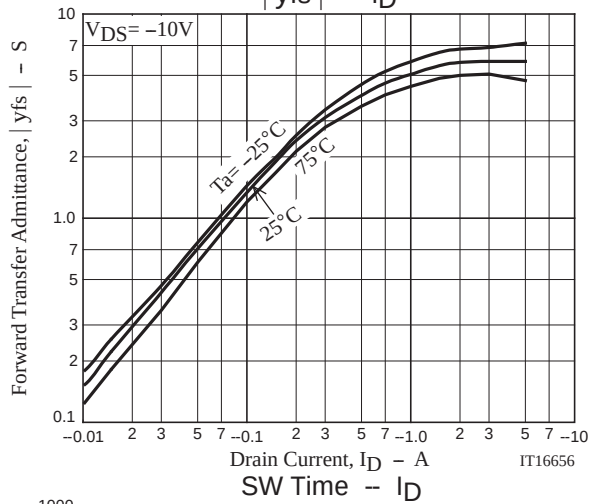
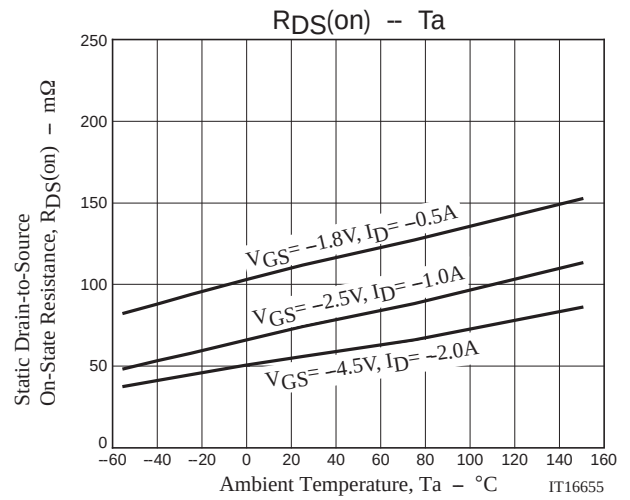
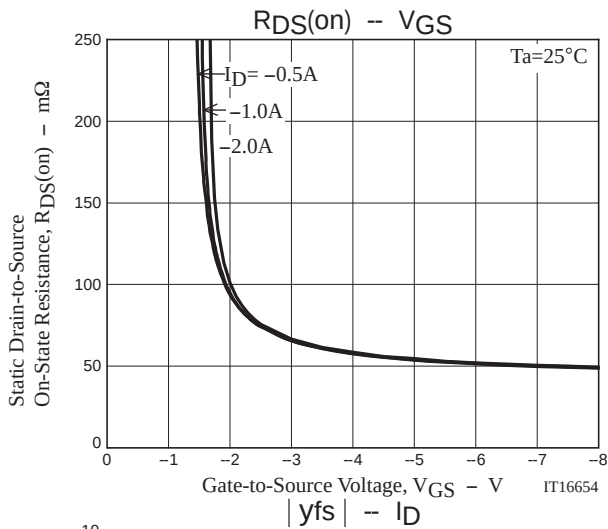
SCH1343

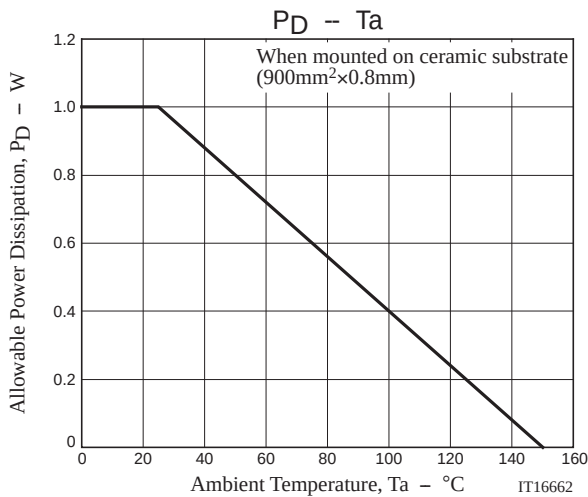
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}$, $V_{GS} = 0\text{V}$	-20			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -20\text{V}$, $V_{GS} = 0\text{V}$			-1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 8\text{V}$, $V_{DS} = 0\text{V}$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{V}$, $I_D = -1\text{mA}$	-0.4		-1.3	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10\text{V}$, $I_D = -2\text{A}$		6		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -2\text{A}$, $V_{GS} = -4.5\text{V}$		55	72	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D = -1\text{A}$, $V_{GS} = -2.5\text{V}$		78	110	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D = -0.5\text{A}$, $V_{GS} = -1.8\text{V}$		115	173	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS} = -10\text{V}$, $f = 1\text{MHz}$		1220		pF
Output Capacitance	C_{oss}			82		pF
Reverse Transfer Capacitance	C_{rss}			72		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		8.8		ns
Rise Time	t_r			35		ns
Turn-OFF Delay Time	$t_d(off)$			123		ns
Fall Time	t_f			61		ns
Total Gate Charge	Q_g	$V_{DS} = -10\text{V}$, $V_{GS} = -4.5\text{V}$, $I_D = -3.5\text{A}$		11		nC
Gate-to-Source Charge	Q_{gs}			1.9		nC
Gate-to-Drain "Miller" Charge	Q_{gd}			1.9		nC
Diode Forward Voltage	V_{SD}	$I_S = -3.5\text{A}$, $V_{GS} = 0\text{V}$		-0.83	-1.2	V

Switching Time Test Circuit







Note on usage : Since the SCH1343 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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